



40V PNP HIGH GAIN TRANSISTOR POWERDI[®]

Features

- $BV_{CEO} > -40V$
- I_C = -3A high Continuous Collector Current
- I_{CM} = -6A Peak Pulse Current
- 43% smaller than SOT223; 60% smaller than TO252
- Maximum Height Just 1.1mm
- Rated up to 3.2W
- Low Saturation, High Gain Transistor,
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

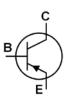
- Case: POWERDI5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.093 grams (approximate)



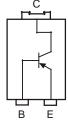




Bottom View



Device Schematic



Top View Pin Out

Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel	
DXT790AP5-13	DXT790A	13	16	5,000	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



DXT790A = Product Type Marking Code The Manufacturers' Code Marking K = Factory Designator YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 09 for 2009) WW = Week code (01 to 53)





DXT790AP5

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-6	V
Continuous Collector Current	Ic	-3	Α
Peak Pulse Current	I _{CM}	-6	A
Base Current	I _B	-0.5	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.2	W	
Power Dissipation	(Note 6)	P_{D}	1.7		
	(Note 7)		0.74		
	(Note 5)		39	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ hetaJA}$	75		
	(Note 7)	*	169		
Thermal Resistance, Junction to Lead	(Note 8)	$R_{ hetaJL}$	8.9	°C/W	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

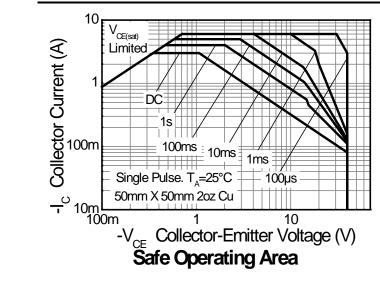
Notes:

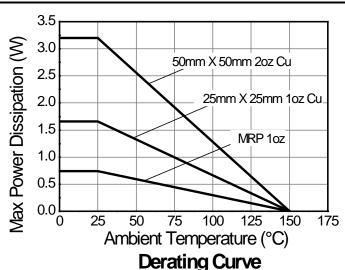
- 5. For a device mounted with the exposed collector pad on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
 7. Same as note (5), except the device is mounted on minimum recommended pad (MRP) layout 1oz copper.

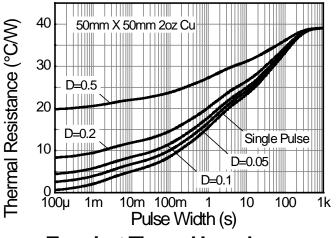
- 8. Thermal resistance from junction to solder-point (on the exposed collector pad).

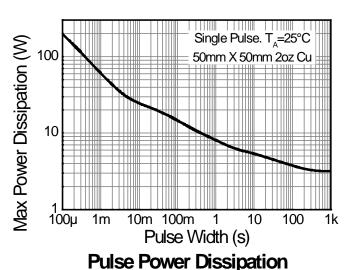


Thermal Characteristics and Derating Information

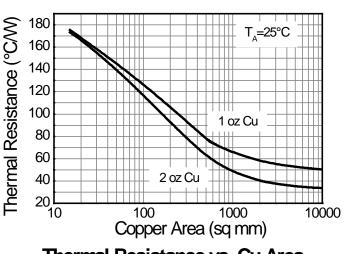


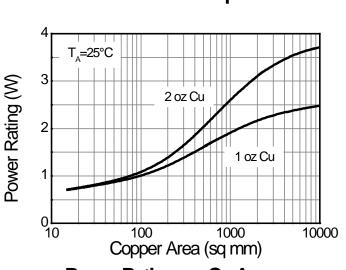






Transient Thermal Impedance





Thermal Resistance vs. Cu Area

Power Rating vs. Cu Area



DXT790AP5

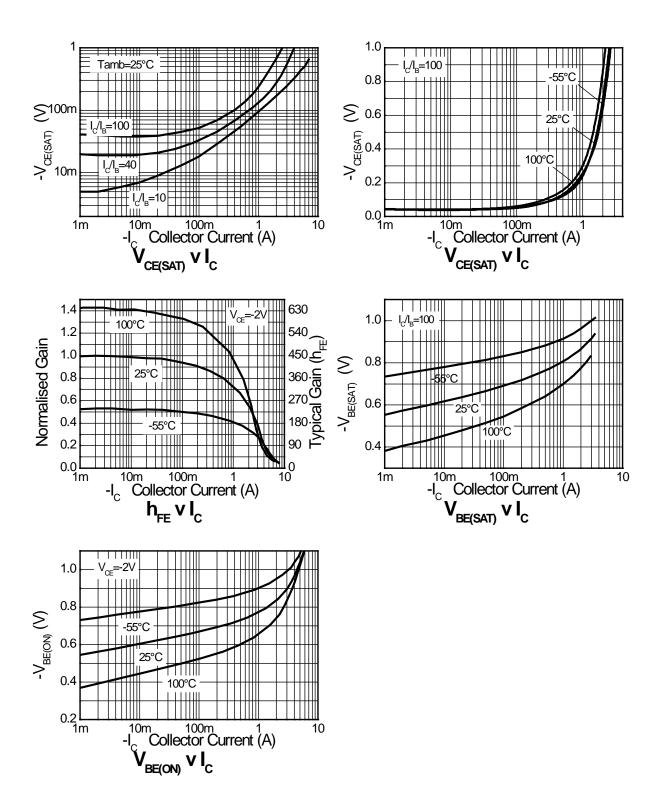
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	-50	_	_	V	$I_C = -100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 8)	BV_{CEO}	-40		_	V	$I_C = -10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV_{EBO}	-6	_	_	V	$I_E = -100\mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}	_	_	-20	nA	$V_{CB} = -30V, I_{E} = 0$
Collector Cutoff Current	ICES	_	_	-20	nA	$V_{CB} = -30V, V_{BE} = 0$
Emitter Cutoff Current	I _{EBO}	_	_	-20	nA	$V_{EB} = -4V, I_{C} = 0$
ON CHARACTERISTICS (Note 8)						
		_	_	-170		$I_C = -0.5A$, $I_B = -5mA$
Collector-Emitter Saturation Voltage	V	_	_	-350	mV	$I_C = -1A$, $I_B = -10mA$
Conector-Entitle Saturation Voltage	V _{CE(sat)}	_	_	-450	IIIV	$I_C = -2A$, $I_B = -50mA$
		_	_	-450		$I_C = -3A$, $I_B = -300mA$
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	_	-1.15	V	$I_C = -3A$, $I_B = -300mA$
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	_	-1.0	V	$I_{C} = -3A$, $V_{CE} = -2V$
	h _{FE}	300	_	800		$I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$
		250	_	_		$I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Gain		200	_	_	_	$I_C = -1A$, $V_{CE} = -2V$
		150	_	_		$I_C = -2A$, $V_{CE} = -2V$
		80	_	_		$I_C = -3A$, $V_{CE} = -2V$
AC CHARACTERISTICS						
Transition Frequency	f _T	100	_	_	MHz	$I_{C} = -50 \text{mA}, V_{CE} = -5 \text{V},$ f = 50 MHz
Output Capacitance	Cobo	_	24	_	рF	V _{CB} = -10V, f = 1MHz
Switching Times	t _{on}	_	35	_	ns	$I_C = -500 \text{mA}, V_{CC} = -10 \text{V},$
Owntoning Times	t _{off}		600		ns	$I_{B1} = -I_{B2} = -50 \text{mA}$

Notes: 8. Measured under pulsed conditions. Pulse width• 300µs. Duty cycle• 2%.



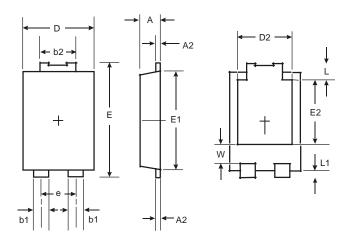
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

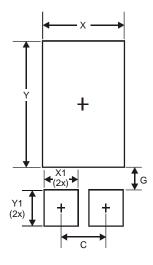
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI5				
Dim	Min	Max		
Α	1.05	1.15		
A2	0.33	0.43		
b1	0.80	0.99		
b2	1.70	1.88		
D	3.90	4.05		
D2	3.054	Тур		
Е	6.40	6.60		
е	1.84	Тур		
E1	5.30	5.45		
E2	3.549 Typ			
L	0.75	0.95		
L1	0.50	0.65		
W	1.10	1.41		
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.840
G	0.852
Х	3.360
X1	1.390
Y	4.860
Y1	1.400





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